

HD14011B

查询HD14011B供应商

捷多邦, 专业PCB打样工厂, 24小时加急

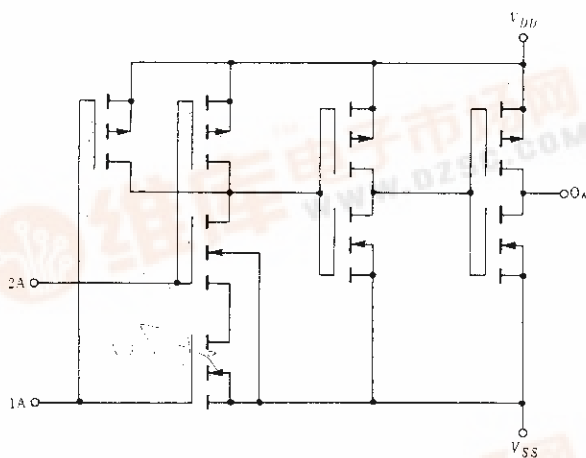
出货

Quadruple 2-input NAND Gate

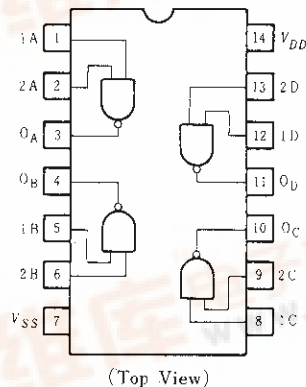
FEATURES

- Quiescent Current = 0.5nA typ/pkg @5V
- Noise Immunity = 45% of V_{DD} typ
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Replacements for CD4011B and MC14011B Series

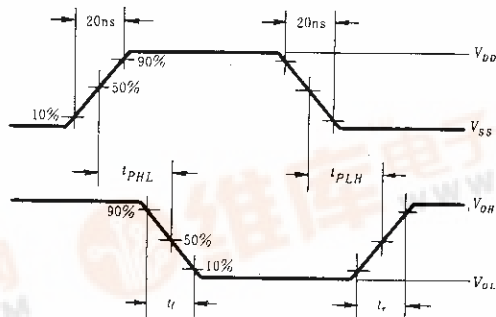
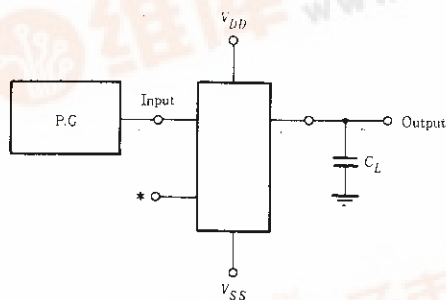
CIRCUIT SCHEMATIC (1/4)



PIN ARRANGEMENT



SWITCHING TIME TEST CIRCUIT



* All unused inputs of AND, NAND gates must be connected to V_{DD} .

■ ELECTRICAL CHARACTERISTICS

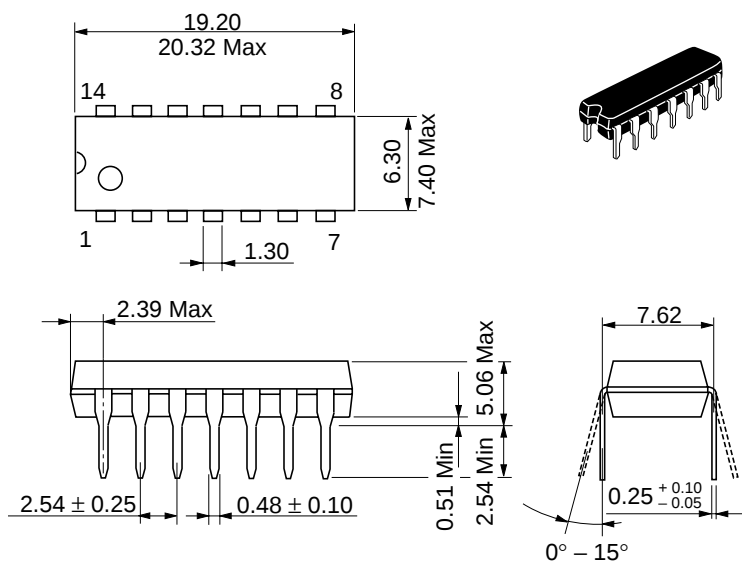
Characteristic	Symbol	Test Conditions	-40°C		25°C			85°C		Unit
			min	max	min	typ	max	min	max	
Output Voltage	V_{OL}	5.0	—	0.05	—	0	0.05	—	0.05	V
		10	—	0.05	—	0	0.05	—	0.05	
		15	—	0.05	—	0	0.05	—	0.05	
	V_{OH}	5.0	4.95	—	4.95	5.0	—	4.95	—	V
		10	9.95	—	9.95	10	—	9.95	—	
		15	14.95	—	14.95	15	—	14.95	—	
Input Voltage	V_{IL}	5.0	—	1.5	—	2.25	1.5	—	1.5	V
		10	—	3.0	—	4.50	3.0	—	3.0	
		15	—	4.0	—	6.75	4.0	—	4.0	
	V_{IH}	5.0	3.5	—	3.5	2.75	—	3.5	—	V
		10	7.0	—	7.0	5.50	—	7.0	—	
		15	11.0	—	11.0	8.25	—	11.0	—	
Output Drive Current	I_{OH}	5.0	—	2.5	—	-2.1	-4.2	—	-1.7	mA
		5.0	-0.52	—	-0.44	-0.88	—	-0.36	—	
		10	-1.3	—	-1.1	-2.25	—	-0.9	—	
		15	-3.6	—	-3.0	-8.8	—	-2.4	—	
	I_{OL}	5.0	0.52	—	0.44	0.88	—	0.36	—	mA
		10	1.3	—	1.1	2.25	—	0.9	—	
		15	3.6	—	3.0	8.8	—	2.4	—	
		15	3.6	—	3.0	8.8	—	2.4	—	
Input Current	I_{in}	15	—	± 0.3	—	± 0.00001	± 0.3	—	± 1.0	μA
Input Capacitance	C_{in}	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current	I_{DD}	5.0	—	1.0	—	0.0005	1.0	—	7.5	μA
		10	—	2.0	—	0.0010	2.0	—	15.0	
		15	—	4.0	—	0.0015	4.0	—	30.0	
Total Supply Current*	I_T	5.0	—	—	—	0.3	—	—	—	μA
		10	—	—	—	0.6	—	—	—	
		15	—	—	—	0.9	—	—	—	

* To calculate total supply current at frequency other than 1kHz.

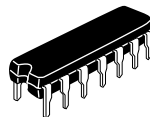
① $V_{DD}=5.0V$ $I_T=0.3\mu A/kHz \cdot f + I_{DD}/4$ ② $V_{DD}=10V$ $I_T=0.6\mu A/kHz \cdot f + I_{DD}/4$ ③ $V_{DD}=15V$ $I_T=0.9\mu A/kHz \cdot f + I_{DD}/4$

■ SWITCHING CHARACTERISTICS ($C_L=50pF$, $T_a=25^\circ C$)

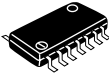
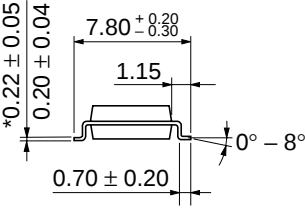
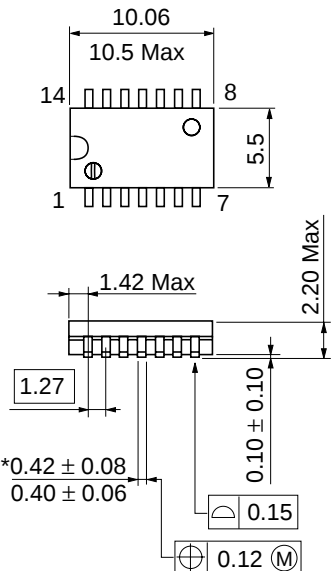
Characteristic	Symbol	$V_{DD}(V)$	min	typ	max	Unit
Output Rise Time	t_r	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Output Fall Time	t_f	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Propagation Delay Time	t_{PLH}	5.0	—	125	250	ns
		10	—	50	100	
		15	—	40	80	
	t_{PHL}	5.0	—	125	250	ns
		10	—	50	100	
		15	—	40	80	



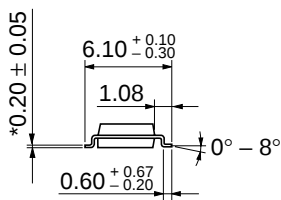
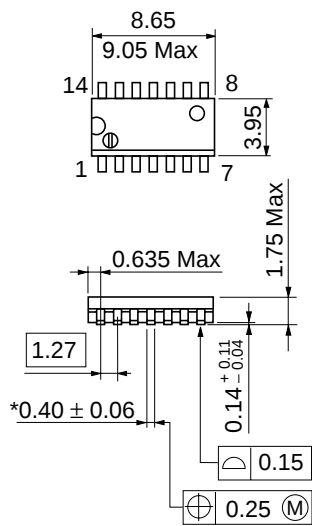
Unit: mm



Unit: mm



Unit: mm



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